

N-channel 80 V 11 m Ω standard level MOSFET in D2PAK

Rev. 2 — 1 March 2012

Product data sheet

1. Product profile

1.1 General description

Standard level N-channel MOSFET in D2PAK package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources

1.3 Applications

Quick reference dete

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- DC-to-DC converters
- Load switching

- Motor control
- Server power supplies

1.4 Quick reference data

| Table 1. | QUICK reference data | | | | | |
|----------------------|---|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | - | - | 80 | V |
| I _D | drain current | $T_{mb} = 25 \text{ °C}; V_{GS} = 10 \text{ V}; \text{ see } \frac{\text{Figure 1}}{10000000000000000000000000000000000$ | - | - | 74 | А |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see <u>Figure 2</u> | - | - | 148 | W |
| Tj | junction temperature | | -55 | - | 175 | °C |
| Static cha | aracteristics | | | | | |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 10 V; I _D = 15 A; T _j = 25 °C | - | 9 | 11 | mΩ |
| Dynamic | characteristics | | | | | |
| Q _{GD} | gate-drain charge | V_{GS} = 10 V; I _D = 25 A; V_{DS} = 40 V; see <u>Figure 14</u> ; see <u>Figure 15</u> | - | 9.4 | - | nC |
| Avalanch | e ruggedness | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 74 A; V_{sup} ≤ 80 V; R_{GS} = 50 Ω; unclamped | - | - | 100 | mJ |
| | | | | | | |

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2. Pinning information

| Table 2. | Pinning | information | | | | | |
|----------|---------|-----------------------------------|--------------------|----------------|--|--|--|
| Pin | Symbol | Description | Simplified outline | Graphic symbol | | | |
| 1 | G | gate | | _ | | | |
| 2 | D | drain ^[1] | mb D | | | | |
| 3 | S | source | | | | | |
| mb | D | mounting base; connected to drain | | mbb076 S | | | |
| | | | SOT404 (D2PAK) | | | | |

[1] It is not possible to make connection to pin 2

3. Ordering information

Table 3.Ordering information

| Type number | Package | | |
|--------------|---------|--|---------|
| | Name | Description | Version |
| PSMN012-80BS | D2PAK | plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404 |

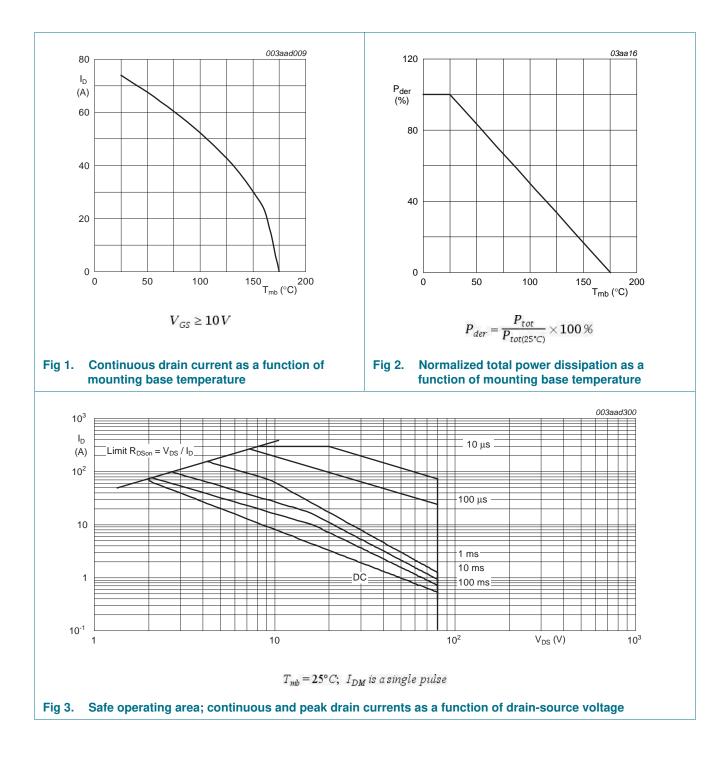
4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------------------|--|---|-----|-----|------|
| V _{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | - | 80 | V |
| V _{DGR} | drain-gate voltage | $T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$ | - | 80 | V |
| V _{GS} | gate-source voltage | | -20 | 20 | V |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 100 °C; see <u>Figure 1</u> | - | 52 | Α |
| | | V_{GS} = 10 V; T_{mb} = 25 °C; see <u>Figure 1</u> | - | 74 | Α |
| I _{DM} | peak drain current | pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; see Figure 3 | - | 295 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see <u>Figure 2</u> | - | 148 | W |
| T _{stg} | storage temperature | | -55 | 175 | °C |
| Tj | junction temperature | | -55 | 175 | °C |
| T _{sld(M)} | peak soldering temperature | | - | 260 | °C |
| Source-dra | ain diode | | | | |
| I _S | source current | T _{mb} = 25 °C | - | 74 | Α |
| I _{SM} | peak source current | pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$ | - | 295 | А |
| Avalanche | ruggedness | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | $ \begin{array}{l} V_{GS} = 10 \; V; \; T_{j(\text{init})} = 25 \; ^{\circ}\text{C}; \; I_{D} = 74 \; A; \\ V_{sup} \leq 80 \; V; \; R_{GS} = 50 \; \Omega; \; \text{unclamped} \end{array} $ | - | 100 | mJ |
| | | | | | |

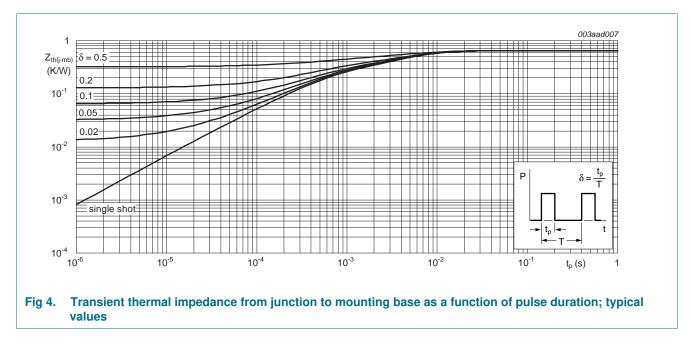
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Thermal characteristics 5.

| Table 5. | Thermal characteristics | | | | | |
|----------------|---|---|-----|------|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | see Figure 4 | - | 0.65 | 1 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | minimum footprint; mounted on a circuit board | - | 50 | - | K/W |



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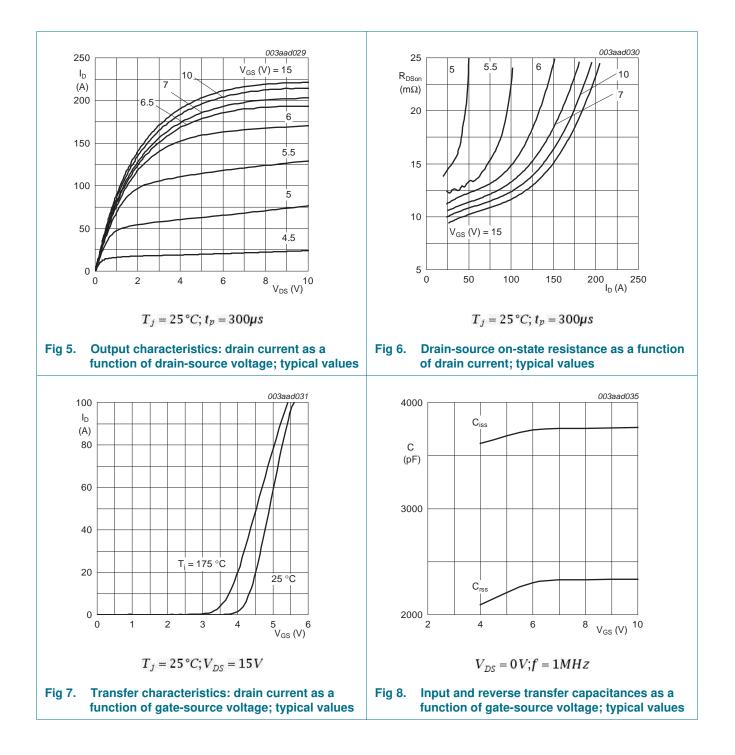
6. Characteristics

Table 6. Characteristics

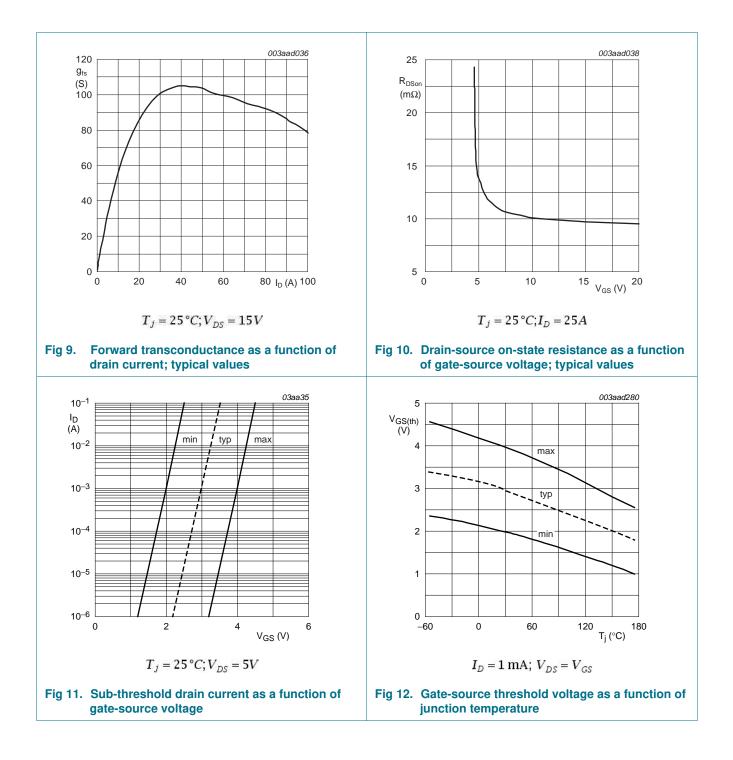
Tested to JEDEC standards where applicable.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|-------------------------------------|---|-----|------|-----|------|
| Static char | acteristics | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | $I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = -55 \ ^{\circ}C$ | 73 | - | - | V |
| | | $I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}C$ | 80 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ see <u>Figure 11</u> ; see <u>Figure 12</u> | 1 | - | - | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ see Figure 11; see Figure 12 | - | - | 4.6 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 11</u> ; see <u>Figure 12</u> | 2 | 3 | 4 | V |
| I _{DSS} | drain leakage current | $V_{DS} = 80 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | - | 3 | μA |
| | | $V_{DS} = 80 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ °C}$ | - | - | 60 | μA |
| I _{GSS} | gate leakage current | V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 100 | nA |
| | | V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 10 V; I_D = 15 A; T_j = 100 °C; see <u>Figure 13</u> | - | - | 18 | mΩ |
| | | V_{GS} = 10 V; I _D = 15 A; T _j = 25 °C | - | 9 | 11 | mΩ |
| R _G | internal gate resistance (AC) | f = 1 MHz | - | 0.97 | - | Ω |
| Dynamic c | haracteristics | | | | | |
| Q _{G(tot)} | total gate charge | $I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$ | - | 36 | - | nC |
| | | $I_D = 25 \text{ A}; V_{DS} = 40 \text{ V}; V_{GS} = 10 \text{ V};$ | - | 43 | - | nC |
| Q_{GS} | gate-source charge | see <u>Figure 14;</u> see <u>Figure 15</u> | - | 12 | - | nC |
| $Q_{GS(th)}$ | pre-threshold gate-source charge | | - | 8 | - | nC |
| Q _{GS(th-pl)} | post-threshold gate-source charge | | - | 4 | - | nC |
| Q _{GD} | gate-drain charge | | - | 9.4 | - | nC |
| V _{GS(pl)} | gate-source plateau voltage | $V_{DS} = 40 V$ | - | 4.5 | - | V |
| C _{iss} | input capacitance | $V_{DS} = 12 V; V_{GS} = 0 V; f = 1 MHz;$ | - | 2782 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C; see <u>Figure 16</u> | - | 384 | - | рF |
| C _{rss} | reverse transfer capacitance | | - | 162 | - | pF |
| t _{d(on)} | turn-on delay time | $V_{DS} = 12 \; V; \; R_L = 0.5 \; \Omega; \; V_{GS} = 10 \; V; \;$ | - | 19 | - | ns |
| t _r | rise time | $R_{G(ext)} = 4.7 \ \Omega$ | - | 16 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 33 | - | ns |
| t _f | fall time | | - | 6 | - | ns |
| Source-dra | ain diode | | | | | |
| V_{SD} | source-drain voltage | $I_{S} = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_{j} = 25 \text{ °C};$ see Figure 17 | - | 0.86 | 1.2 | V |
| t _{rr} | reverse recovery time | $I_{S} = 50 \text{ A}; dI_{S}/dt = 100 \text{ A}/\mu\text{s};$ | - | 45 | - | ns |
| Q _r | recovered charge | $V_{GS} = 0 V; V_{DS} = 40 V$ | - | 64 | - | nC |

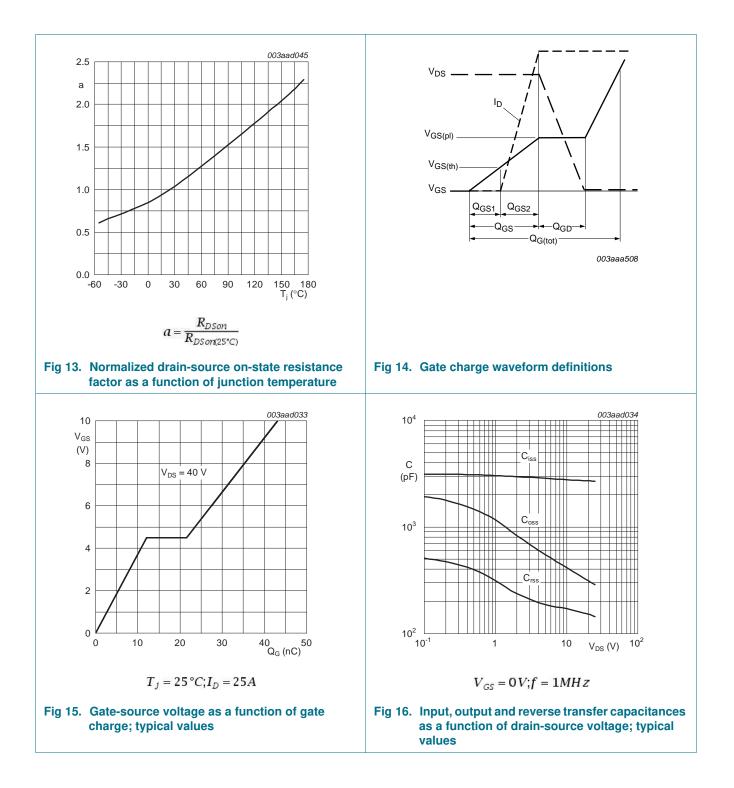
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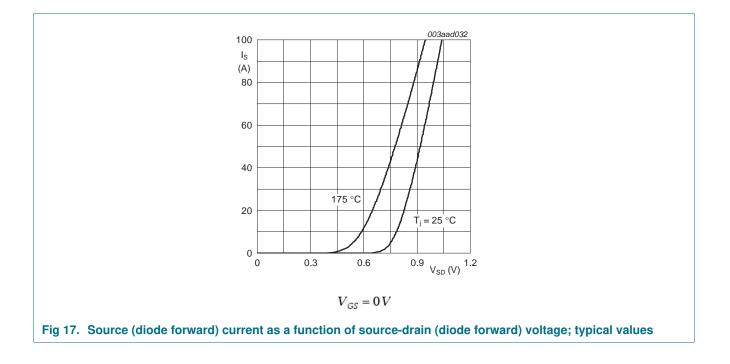
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7. Package outline

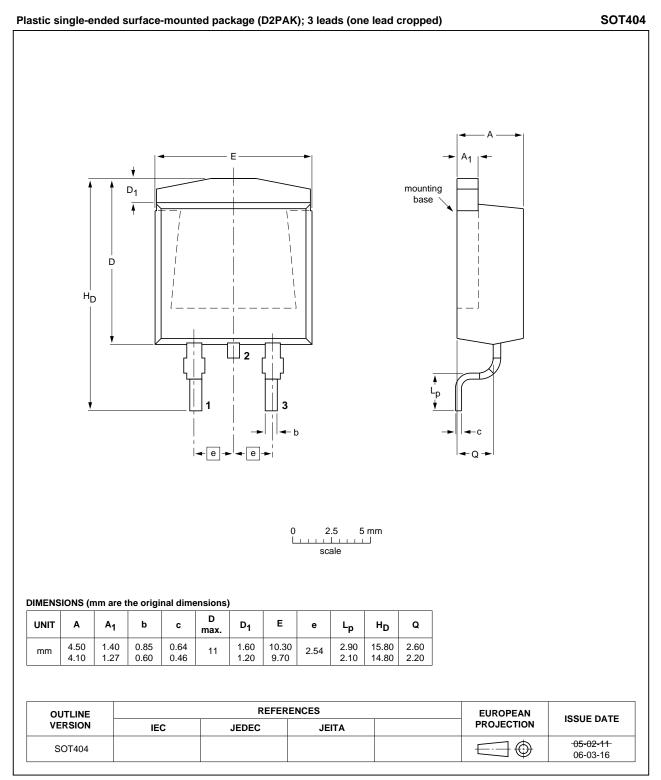


Fig 18. Package outline SOT404 (D2PAK)

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8. Revision history

| Table 7.Revision h | nistory | | | |
|--------------------|-----------------------------------|------------------------------|---------------|------------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| PSMN012-80BS v.2 | 20120301 | Product data sheet | - | PSMN012-80BS v.1 |
| Modifications: | Status change | d from objective to product. | | |
| | Various chang | es to content. | | |
| PSMN012-80BS v.1 | 20111024 | Objective data sheet | - | - |

9. Legal information

9.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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